



P-Channel 40-V (D-S) MOSFET

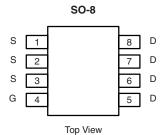
PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)			
- 40	0.0155 at V _{GS} = - 10 V	- 10.5			
	$0.0225 \text{ at V}_{GS} = -4.5 \text{ V}$	- 8.7			

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFETs

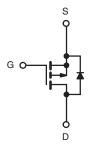


FREE



Ordering Information: Si4401DY-T1-E3 (Lead (Pb)-free)

Si4401DY-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 40		V	
Gate-Source Voltage		V _{GS}	± 20			
0 11 0 1/2 1/2 1/2 1/2	T _A = 25 °C	- I _D	- 10.5	- 8.7		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 8.3	- 5.9		
Pulsed Drain Current		I _{DM}	- 50		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	- 2.7	- 1.36		
Maximum Power Dissipation ^a	T _A = 25 °C	D	3.0	1.5	W	
	T _A = 70 °C	- P _D	1.9	0.95	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mariana basilian ta Ambianti	t ≤ 10 s	- R _{thJA}	33	42	°C/W
Maximum Junction-to-Ambient ^a	Steady State		70	84	
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	16	21	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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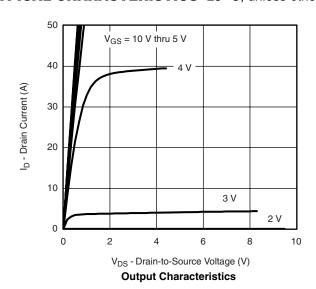
SPECIFICATIONS T _J = 25 °C, unless otherwise noted								
Parameter	Symbol	Test Conditions M		Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	- 1.0			V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -32 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = -32 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 \text{ °C}$			- 1	μΑ		
					- 10			
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 10 V	- 30			Α		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 10.5 A	0.013 0.		0.0155			
		$V_{GS} = -4.5 \text{ V}, I_D = -8.7 \text{ A}$		0.0185	0.0225	Ω		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 10.5 A		26		S		
Diode Forward Voltage ^a	V_{SD}	I _S = - 2.7 A, V _{GS} = 0 V		- 0.74	- 1.1	V		
Dynamic ^b								
Total Gate Charge	Q_g			37.5	50			
Gate-Source Charge	Q_{gs}	$V_{DS} = -15 \text{ V}, V_{GS} = -5 \text{ V}, I_{D} = -10.5 \text{ A}$		14.3		nC		
Gate-Drain Charge	Q_{gd}			10.7				
Turn-On Delay Time	t _{d(on)}			17	30			
Rise Time	t _r	V_{DD} = - 15 V, R_L = 15 Ω		18	30	ns		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ - 1 A, V_{GEN} = - 10 V, R_g = 6 Ω		122	190			
Fall Time	t _f			55	85			
Gate Resistance	R_{g}			3.8		Ω		
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = -2.1 \text{ A}, dI/dt = 100 \text{ A/}\mu\text{s}$		45		ns		

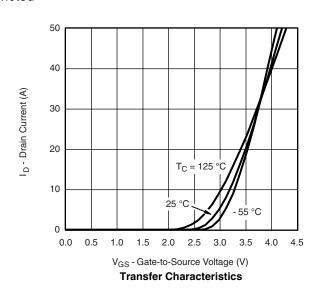
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



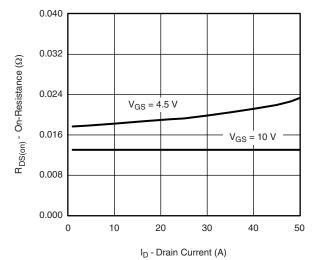




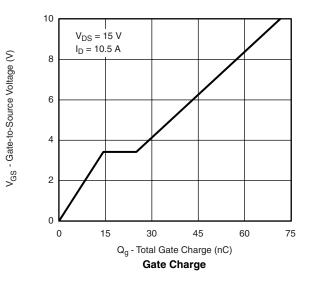


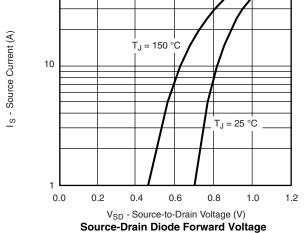


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



On-Resistance vs. Drain Current

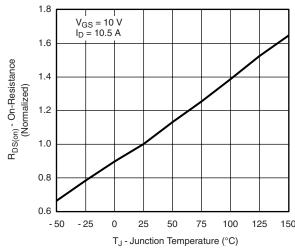




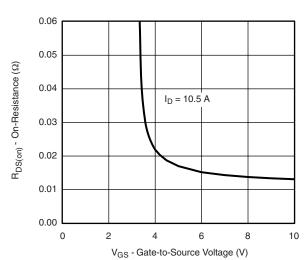
6500 C_{iss} S200 C_{iss} C_{rss} C_{rss} 0 0 0 6 12 18 24 30

V_{DS} - Drain-to-Source Voltage (V)





On-Resistance vs. Junction Temperature



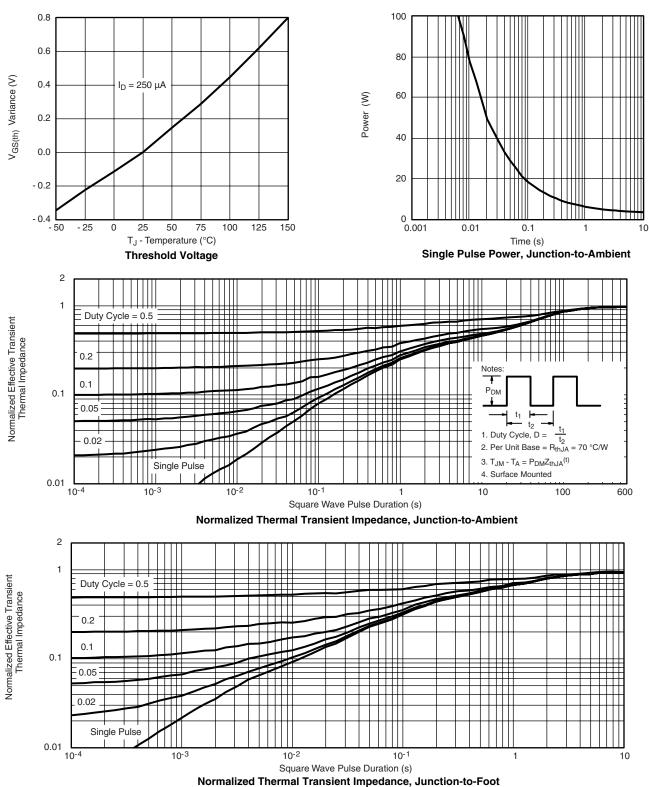
On-Resistance vs. Gate-to-Source Voltage

50

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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